Unit: mm



TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOSVI-H)

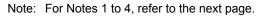
# **TPCA8047-H**

Switching Regulator Applications Motor Drive Applications DC-DC Converter Applications

- Small footprint due to a small and thin package
- High-speed switching
- Small gate charge: Q<sub>SW</sub> = 13 nC (typ.)
- Low drain-source ON-resistance:  $R_{DS}(ON) = 4.8 \text{ m}\Omega$  (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 92 S$  (typ.)
- Low leakage current:  $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 40 \ V)$
- Enhancement mode:  $V_{th}$  = 1.3 to 2.3 V (V\_{DS} = 10 V,  $I_{D}$  = 0.5 mA)

#### Absolute Maximum Ratings (Ta = 25°C)

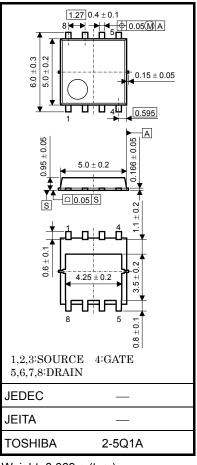
Characte	ristic	Symbol	Rating	Unit	
Drain-source voltage		V <sub>DSS</sub>	40	V	
Drain-gate voltage (R	l <sub>GS</sub> = 20 kΩ)	V <sub>DGR</sub>	40	V	
Gate-source voltage		V <sub>GSS</sub>	±20	V	
Drain current	DC (Note 1)	۱ <sub>D</sub>	32	А	
Drain current	Pulsed (Note 1)	I <sub>DP</sub>	96	A	
Drain power dissipati	on (Tc = 25°C)	PD	45	W	
Drain power dissipati	on (t = 10 s) (Note 2a)	PD	2.8	W	
Drain power dissipati	on (t = 10 s) (Note 2b)	PD	1.6	W	
Single-pulse avalance	ne energy (Note 3)	E <sub>AS</sub>	95	mJ	
Avalanche current		I <sub>AR</sub>	32	А	
Repetitive avalanche (To	energy c = 25°C) (Note 4)	E <sub>AR</sub>	3.95	mJ	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature	range	T <sub>stg</sub>	–55 to 150	°C	



Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the

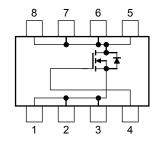
reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.069 g (typ.)

#### **Circuit Configuration**



Start of commercial production 2008-10

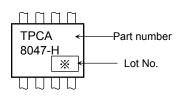
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### Thermal Characteristics

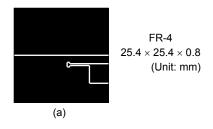
Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case (Tc = 25°C)	R <sub>th (ch-c)</sub>	2.78	°C/W
Thermal resistance, channel to ambient $(t = 10 \text{ s})$ (Note 2a)	R <sub>th (ch-a)</sub>	44.6	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R <sub>th (ch-a)</sub>	78.1	°C/W

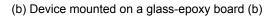
### Marking (Note 5)

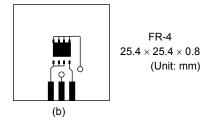


Note 1: Ensure that the channel temperature does not exceed 150  $^\circ\text{C}.$ 

Note 2: (a) Device mounted on a glass-epoxy board (a)







- Note 3:  $V_{DD} = 24 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}$  (initial), L = 100  $\mu$ H, R<sub>G</sub> = 25  $\Omega$ , I<sub>AR</sub> = 32 A
- Note 4: Repetitive rating: pulse width limited by maximum channel temperature
- Note 5: \* Weekly code: (Three digits)



Week of manufacture (01 for the first week of the year, continuing up to 52 or 53) Year of manufacture

(The last digit of the year)

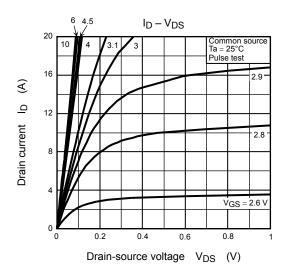
Electrical Characteristics (Ta = 25°C)

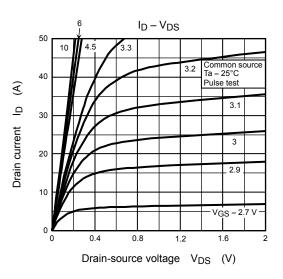
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I <sub>GSS</sub>	$V_{GS}=\pm 20~V,~V_{DS}=0~V$	_		±100	nA
Drain cutoff curre	ent	I <sub>DSS</sub>	$V_{DS} = 40 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_		10	μA
Drain source bro	rain-source breakdown voltage		$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	40	_	_	V
Drain-source brea	akuown vollage	V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	25		_	v
Gate threshold vo	oltage	V <sub>th</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 0.5 \text{ mA}$	1.3 — 2.3		V	
Drain-source ON	rosistanco	Pro (ou)	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 16 \text{ A}$	_	6.0	8.5	mΩ
Drain-source ON	resistance	R <sub>DS</sub> (ON)	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 16 \text{ A}$	25            1.3	1115.2		
Forward transfer	admittance	Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 16 \text{ A}$	46	92	_	S
Input capacitance	9	C <sub>iss</sub>		_	2590	3365	
Reverse transfer capacitance		C <sub>rss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	135	200	pF
Output capacitance		C <sub>oss</sub>		_	440	_	
Gate resistance		rg	$V_{DS}$ = 10 V, $V_{GS}$ = 0 V, f = 1 MHz	_	1.0	1.5	Ω
	Rise time	tr	$V_{GS} \stackrel{10}{}_{0}V \qquad I_{D} = 16 A$ $V_{GS} \stackrel{10}{}_{0}V \qquad G_{S} \stackrel{10}{}_{C} \stackrel{10}{}_{C}$	_	4.8	_	ns
Switching time	Turn-on time	t <sub>on</sub>		_	13	_	
	Fall time	t <sub>f</sub>		_	9.9	_	
	Turn-off time	t <sub>off</sub>	$V_{DD}\approx 20 \text{ V}$ Duty $\leq$ 1%, $t_W=10 \ \mu s$		43	_	
Total gate charge	Total gate charge		$V_{DD} \approx 32 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 32 \text{ A}$		43	_	
(gate-source plus	s gate-drain)	Qg	$V_{DD}\approx 32~V,~V_{GS}=5~V,~I_{D}=32~A$	23		_	
Gate-source charge 1		Q <sub>gs1</sub>	$V_{DD} \approx 32 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 32 \text{ A}$		7.9	_	nC
Gate-drain ("Miller") charge		Q <sub>gd</sub>			8.4		
Gate switch char	ge	Q <sub>SW</sub>	1	_	13	_	

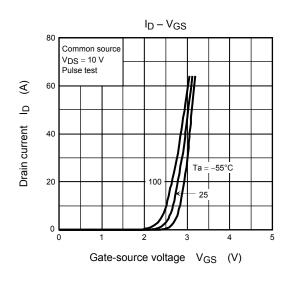
#### Source-Drain Ratings and Characteristics (Ta = 25°C)

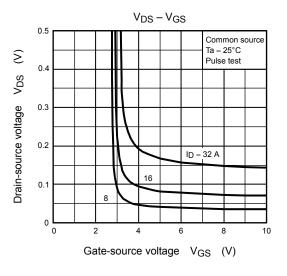
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit	
Drain reverse current	Pulse	(Note 1)	I <sub>DRP</sub>	—	_	_	96	А
Forward voltage (diode)			V <sub>DSF</sub>	$I_{DR} = 32 \text{ A}, V_{GS} = 0 \text{ V}$			-1.2	V

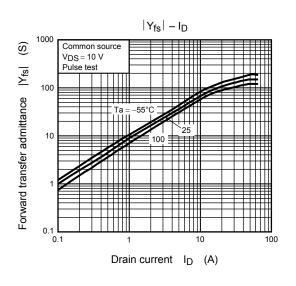
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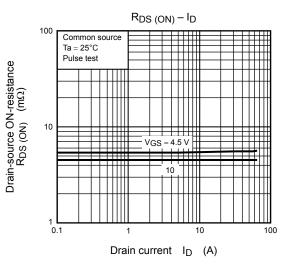




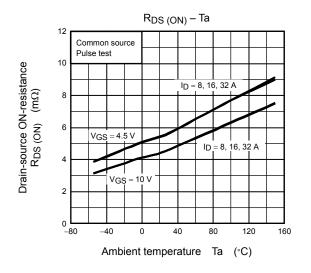


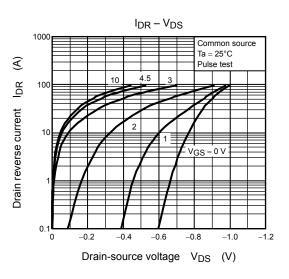


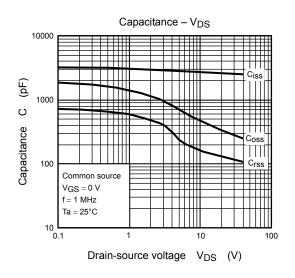


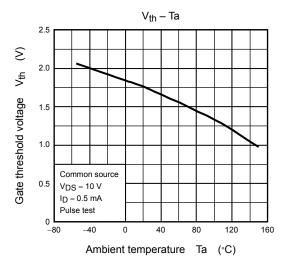


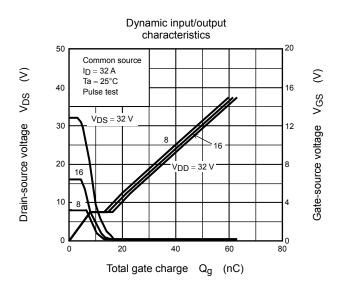
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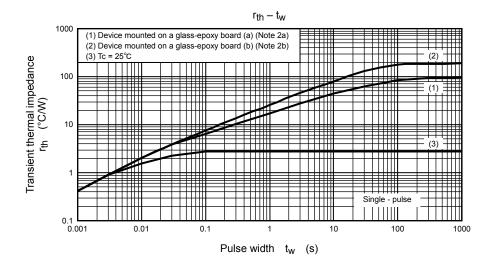


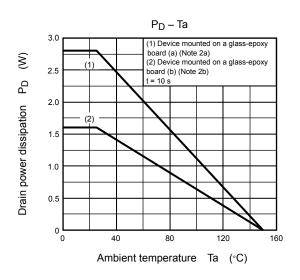


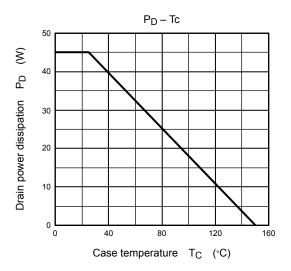


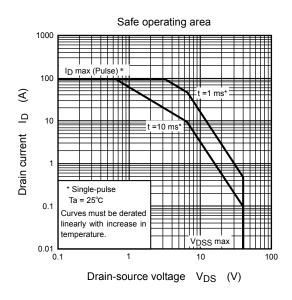












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